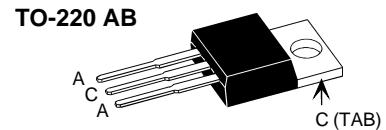
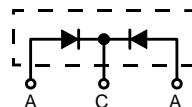


Power Schottky Rectifier with common cathode

I_{FAV} = 2x10 A
V_{RRM} = 45 V
V_F = 0.45 V

| V _{RSM} | V _{RRM} | Type |
|------------------|------------------|---------------|
| V | V | |
| 45 | 45 | DSSK 20-0045B |



A = Anode, C = Cathode , TAB = Cathode

| Symbol | Conditions | Maximum Ratings | |
|-----------------------|--|-----------------|------|
| I _{FRMS} | | 35 | A |
| I _{FAV} | T _C = 135°C; rectangular, d = 0.5 | 10 | A |
| I _{FAV} | T _C = 135°C; rectangular, d = 0.5; per device | 20 | A |
| I _{FSM} | T _{VJ} = 45°C; t _p = 10 ms (50 Hz), sine | 160 | A |
| E _{AS} | I _{AS} = 13 A; L = 180 µH; T _{VJ} = 25°C; non repetitive | 24 | mJ |
| I _{AR} | V _A = 1.5 • V _{RRM} typ.; f=10 kHz; repetitive | 1.3 | A |
| (dv/dt) _{cr} | | 1000 | V/µs |
| T _{VJ} | | -55...+150 | °C |
| T _{VJM} | | 150 | °C |
| T _{stg} | | -55...+150 | °C |
| P _{tot} | T _C = 25°C | 75 | W |
| M _d | mounting torque | 0.4...0.6 | Nm |
| Weight | typical | 2 | g |

| Symbol | Conditions | Characteristic Values | |
|--|---|-----------------------|-------------------|
| | | typ. | max. |
| I _R ① | T _{VJ} = 25°C V _R = V _{RRM} T _{VJ} = 100°C V _R = V _{RRM} | 5 50 | mA mA |
| V _F | I _F = 10 A; T _{VJ} = 125°C I _F = 10 A; T _{VJ} = 25°C I _F = 20 A; T _{VJ} = 125°C | 0.45 0.51 0.70 | V V V |
| R _{thJC} R _{thCH} | | 0.5 | 1.7 K/W K/W |

Features

- International standard package
- Very low V_F
- Extremely low switching losses
- Low I_{RM}-values
- Epoxy meets UL 94V-0

Applications

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Advantages

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses

Dimensions see outlines.pdf

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0 %
Data according to IEC 60747 and per diode unless otherwise specified

IXYS reserves the right to change limits, Conditions and dimensions.

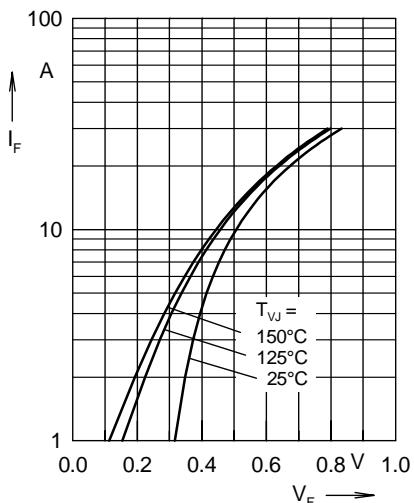


Fig. 1 Maximum forward voltage drop characteristics

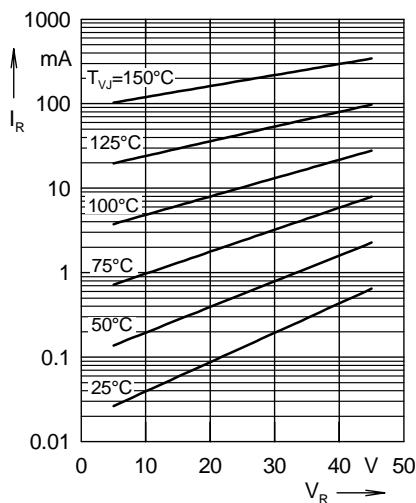


Fig. 2 Typ. value of reverse current I_R versus reverse voltage V_R

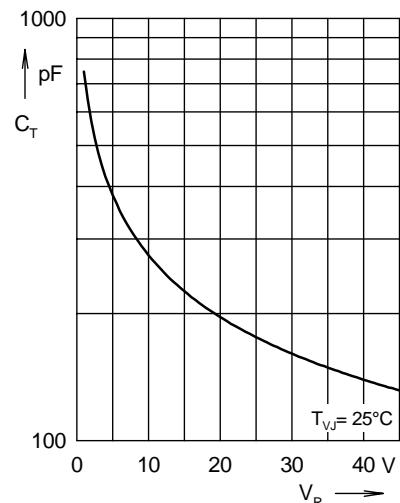


Fig. 3 Typ. junction capacitance C_T versus reverse voltage V_R

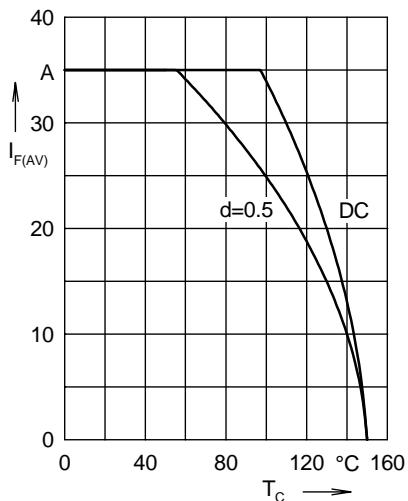


Fig. 4 Average forward current $I_{F(AV)}$ versus case temperature T_C

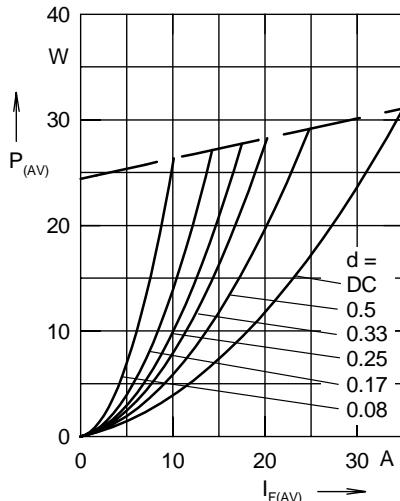


Fig. 5 Forward power loss characteristics

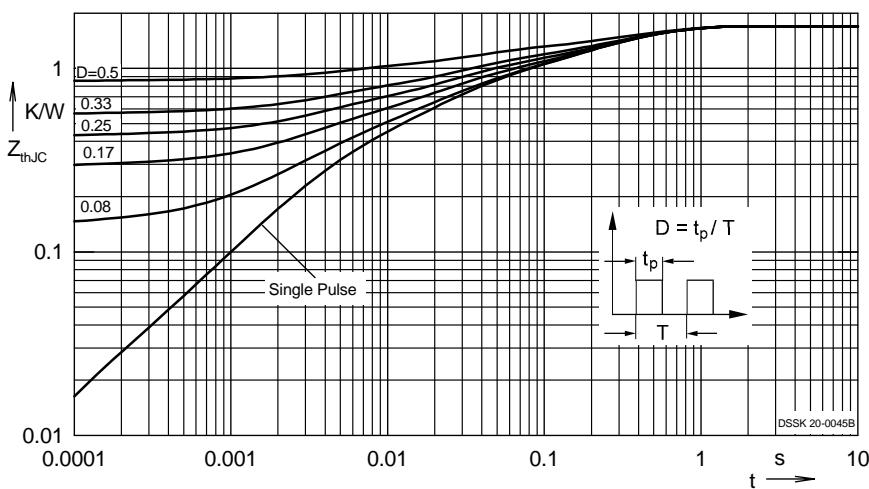


Fig. 6 Transient thermal impedance junction to case at various duty cycles

Note: All curves are per diode

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